TOSHIBA Photocoupler IRED + Photo IC

TLP750

Digital Logic Ground Isolation
Line Receiver
Microprocessor System Interfaces
Switching Power Supply Feedback Control
Analog Signal Isolation
Transistor Inverter

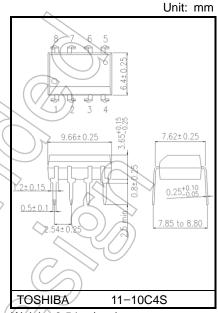
The TOSHIBA TLP750 consists of a high-output infrared light emitting diode optically coupled to a high-speed photodiode with a transistor amplifier and is housed in an 8-pin DIP.

The TLP750 has no internal base connection and features noise immunity, thus it is suitable for inverter drivers for variable-speed motor drives.

- Switching speed: t_{pHL}=0.3μs (typ.)
- Switching speed: $t_{pLH}=0.5\mu s$ (typ.) (RL=1.9k Ω)
- Isolation voltage: 5000 V_{rms} (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

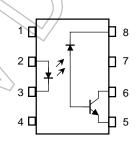
Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

• Creepage distance: 6.4mm (min)
Clearance: 6.4mm (min)
Insulation thickness: 0.4mm (min)



Weight: 0.54 g (typ.)

Pin Configuration (top view)



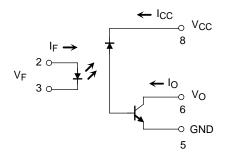
1 : N.C.2 : Anode

3 : Cathode 4 : N.C.

5 : Emitter6 : Collector

7 : N.C. 8 : (V_{CC}

Schematic



Start of commercial production 1989-10

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit	
LED	Forward current	(Note 1)	lF	25	mA	
	Pulse forward current	(Note 2)	lFP	50	mA	
	Peak transient forward current	(Note 3)	I _{FPT}	1	Α	
	Reverse voltage		VR	5	V	
	Diode power dissipation	(Note 4)	PD	45	mW	
	Output current		lo	8	mA	
Detector	Peak output current		IOP	(16)	mA	
	Output voltage		Vo (-0.5 to 15	V	
	Supply voltage		Vcc	-0.5 to 15	V	
	Output power dissipation	(Note 5)	Po	100	mW	
Operating temperature range			Topr	-55 to 100	\@C	
Storage temperature range			T _{stg}	-55 to 125	~c	
Lea	d solder temperature(10 s)	(Note 6)	Tsøl	260	Ç.C	
Isolation voltage (AC, 60 s, R.H.= 60 %)		(Note 7)	BVs	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- (Note 1) Derate 0.8 mA / °C above 70 °C.
- (Note 2) 50 % duty cycle, 1ms pulse width.

 Derate 1.6 mA / °C above 70 °C.
- (Note 3) Pulse width ≤ 1 µs, 300 pps.
- (Note 4) Derate 0.9 mW / °C above 70 °C.
- (Note 5) Derate 2 mW / °C above 70 °C.
- (Note 6) Soldering portion of lead: Up to 2mm from the body of the device.
- (Note 7) Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	VF	I _F = 16 mA	_	1.65	1.85	V
	Forward voltage temperature coefficient	ΔV _F / ΔTa	I _F = 16 mA	1	-2	_	mV / °C
	Reverse current	I _R	V _R = 5 V		_	10	μА
	Capacitance between terminal	Ст	V _F = 0 V, f = 1 MHz		45	_	pF
Detector		IOH(1)	I _F = 0 mA, V _{CC} = V _O = 5.5 V		3	500	nA
	High level output current	I _{OH(2)}	IF = 0 mA, V _{CC} = V _O = 15 V			5	μΑ
	Іон		$I_F = 0 \text{ mA}, V_{CC} = V_O = 15 \text{ V},$ Ta = 70 °C	2_	_	50	μА
	High level supply voltage	Іссн	I _F = 0 mA, V _{CC} = 15 V	_	0.01	1	μА
Coupled/ Insulation	Current transfer ratio	I _O /I _F	Ta = 25° C	10 19 5	30	<u> </u>	%
	Low level output voltage	V _{OL}	IF = 16 mA, V _{CC} = 4.5 V, IO = 1.1 mA (rank O: IO = 2.4 mA)	7	70/	0.4	V
	Isolation resistance	Rs	R.H.≤ 60 %, V _S = 500 V _{DC} (Note 7)	1×10 ¹²	10 ¹⁴	_	Ω
	Capacitance between input to output	Cs	$\overline{V}_S = 0 \text{ V}, f = 1 \text{ MHz}$ (Note 7)		0.8		pF
	Isolation Voltage	BVs	AC, 60 s (Note 7)	5000	_		Vrms

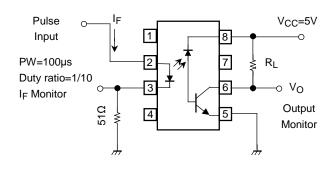
Switching Characteristics (Ta = 25°C, Vcc = 5V)

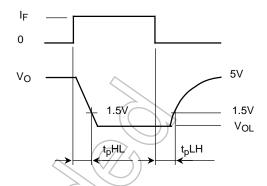
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H→L)	to HL	1	IF = 16 mA, R_L = 4.1 k Ω	_	0.2	8.0	0
Propagation delay time (HPL)			Rank O: R _L =1.9 kΩ		0.3	8.0	μ\$
Propagation delay time (L→H)	t _{pLH}		$I_F = 16 \text{ mA}, R_L = 4.1 \text{ k}\Omega$		1	2	
Propagation delay time (L->h)			Rank O: R _L = 1.9 kΩ	_	0.5	1.2	μS
Common mode transient immunity at logic high output (Note 8)	СМН	2	I_F = 0 mA, V_{CM} = 200 V_{p-p} R _L =4.1 kΩ (Rank O: R _L = 1.9 kΩ)	ı	1500		V / μs
Common mode transient immunity at logic low output (Note 8)	CML	2	I _F = 16 mA, V_{CM} = 200 V_{p-p} R _L = 4.1 kΩ (Rank O: R _L = 1.9 kΩ)	-	-1500	_	V / μs

(Note 8) CML is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (VO < 0.8 V).

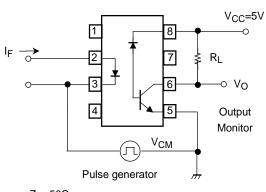
CMH is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state (VO > 2.0 V).

Test Circuit 1: Switching Time Test Circuit



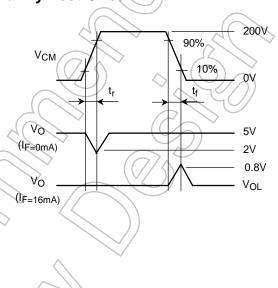


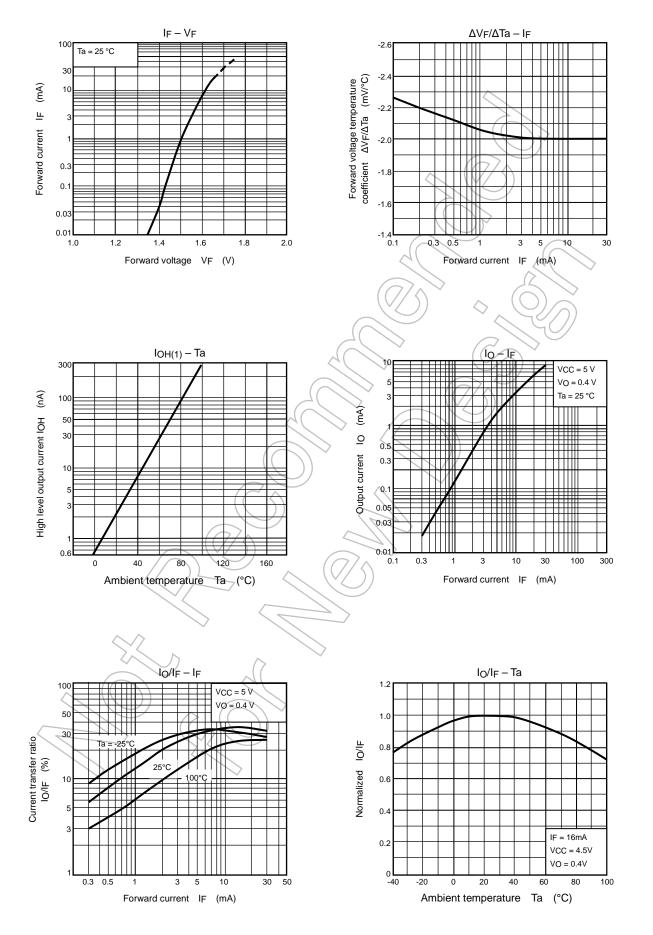
Test Circuit 2: Common Mode Noise Immunity Test Circuit



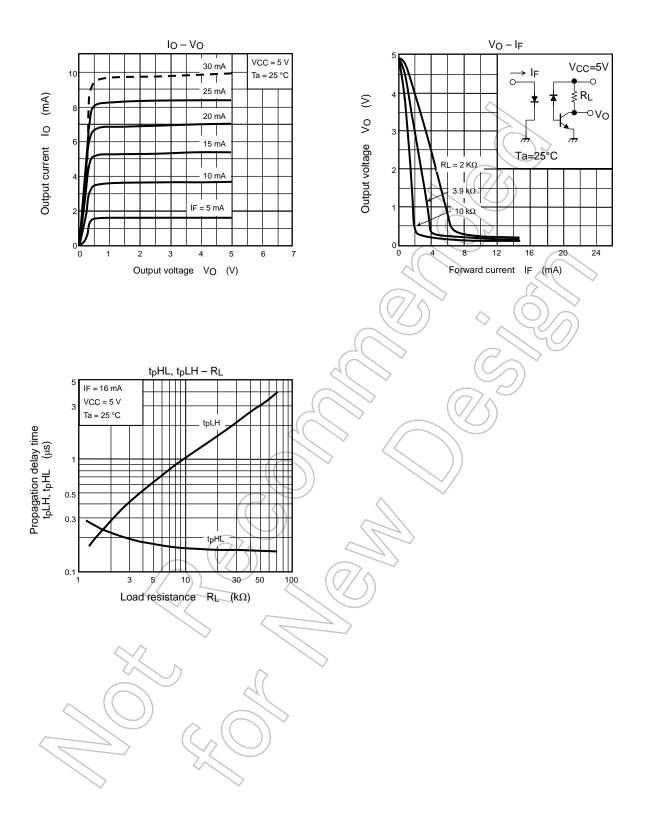
 $Z_O=50\Omega$

$$CM_{H} = \frac{160(V)}{t_{\Gamma}(\mu s)}, CM_{L} = \frac{160(V)}{t_{f}(\mu s)}$$





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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